



## UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE  
 United States Patent and Trademark Office  
 Address: COMMISSIONER FOR PATENTS  
 P.O. Box 1450  
 Alexandria, Virginia 22313-1450  
 www.uspto.gov



Bib Data Sheet

CONFIRMATION NO. 7172

<b>SERIAL NUMBER</b> 10/726,507	<b>FILING OR 371(c) DATE</b> 12/04/2003 <b>RULE</b>	<b>CLASS</b> 257	<b>GROUP ART UNIT</b> 2815	<b>ATTORNEY DOCKET NO.</b> 843.43311X00
------------------------------------	---	---------------------	-------------------------------	--

## APPLICANTS

Digh Hisamoto, Kokubunji, JAPAN;  
 Shinichiro Kimura, Kunitachi, JAPAN;  
 Kan Yasui, Kodaira, JAPAN;  
 Nozomu Matsuzaki, Kokubunji, JAPAN;

\*\* CONTINUING DATA \*\*\*\*\*

\*\* FOREIGN APPLICATIONS \*\*\*\*\*

JAPAN P2002-352040 12/04/2002

IF REQUIRED, FOREIGN FILING LICENSE GRANTED

\*\* 03/12/2004

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input checked="" type="checkbox"/> no	<b>STATE OR COUNTRY</b> JAPAN	<b>SHEETS DRAWING</b> 22	<b>TOTAL CLAIMS</b> 21/6	<b>INDEPENDENT CLAIMS</b> 7
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input checked="" type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged Examiner's Signature: <i>[Signature]</i> Initials: <i>[Initials]</i>				

## ADDRESS

020457

## TITLE

Fabrication method and structure of semiconductor non-volatile memory device

<b>FILING FEE RECEIVED</b> 1132	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees
		<input type="checkbox"/> 1.16 Fees ( Filing )
		<input type="checkbox"/> 1.17 Fees ( Processing Ext. of time )
		<input type="checkbox"/> 1.18 Fees ( Issue )
		<input type="checkbox"/> Other _____
		<input type="checkbox"/> Credit